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ICE ROSPINSE
DSMalls-LOGON
1-28-03

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

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In re Applicant:

Harry Q. Pon

Serial No.:

09/836,973

Filed:

April 18, 2001

For:

EMI and Noise Shielding for Multi-

Metal Layer High Frequency

**Integrated Circuit Processes** 

Commissioner for Patents Washington, D.C. 20231

Art Unit: 2823

Examiner: Deven Collins

Atty Docket: ITL.0452US

P9563

TECHNOLOGY CENTER 2800

## **REPLY TO PAPER NO. 4**

In response to the Office Action mailed December 4, 2002, the Applicant requests the Examiner to please consider the following remarks as follows:

## REMARKS

Claims 13-15, 18, 20-21, 24, and 26-29 were rejected under 35 U.S.C. § 102(b) as anticipated by Pan et al. (U.S. Pat. No. 6,051,869).

Independent claim 13 recites an integrated circuit having a semiconductor substrate, an interconnection layer positioned over said substrate, a passive circuit element between said substrate and said interconnection layer, and a trench that encircles said passive circuit element, said trench filled with a conductive material.

The Applicant requests reconsideration and withdrawal of the rejection of claim 13 under 35 U.S.C. § 102(b) because Pan fails to teach or suggest an integrated circuit having a trench that encircles said passive circuit element, said trench filled with a conductive material.

Pan describes an integrated circuit and method for making it. The integrated circuit includes an insulating layer, formed within a trench that separates conductive elements of a conductive layer. (See, col. 3, line 14 - col. 4, line 10). Unlike the trench described in independent claim 13, the integrated circuit described by Pan does not have a trench that encircles said passive circuit element, said trench filled with a conductive material. The trench described by Pan is filled with an insulating material, rather than a conductive material.

Date of Deposit: JANUARY 15, 2003 I hereby certify under 37 CFR 1.8(a) that this correspondence is being deposited with the United States Postal Service as First Class Mail with sufficient postage on the date indicated above and is addressed to the Commissioner for Patents, Washington, D.C. 20231.

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